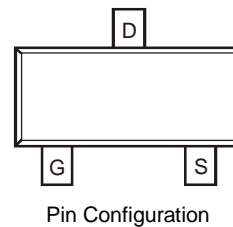
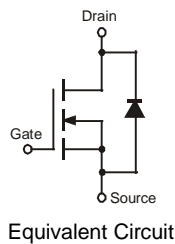


Features

- Low Gate Charge
- Low $R_{DS(ON)}$:
 - $30m\Omega$ @ $V_{GS} = 10V$
 - $40m\Omega$ @ $V_{GS} = 4.5V$
- Low Input/Output Leakage
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

- Case: SC59
- Case Material - Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 **(e3)**
- Terminal Connections: See Diagram
- Weight: 0.014 grams (Approximate)

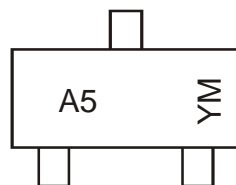


Ordering Information (Note 4)

| Part Number | Case | Packaging |
|--------------|------|------------------|
| DMN3033LSN-7 | SC59 | 3000/Tape & Reel |

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



A5 = Product Type Marking Code
 YM = Date Code Marking
 Y = Year (ex: D = 2016)
 M = Month (ex: 9 = September)

Date Code Key

| Year | 2007 | ~ | 2016 | 2017 | 2018 | 2019 | 2020 | 2021 | 2022 |
|------|------|---|------|------|------|------|------|------|------|
| Code | U | ~ | D | E | F | G | H | I | J |

| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
|-------|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | O | N | D |

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|----------------------------------------|------------------|------------------------|------|
| Drain-Source Voltage | V _{DSS} | 30 | V |
| Gate-Source Voltage | V _{GSS} | ±20 | V |
| Continuous Drain Current (Note 5) | I _D | T _A = +25°C | 6 |
| | | T _A = +70°C | 5 |
| Pulsed Drain Current (Note 6) | I _{DM} | 24 | A |
| Body-Diode Continuous Current (Note 5) | I _S | 2.25 | A |

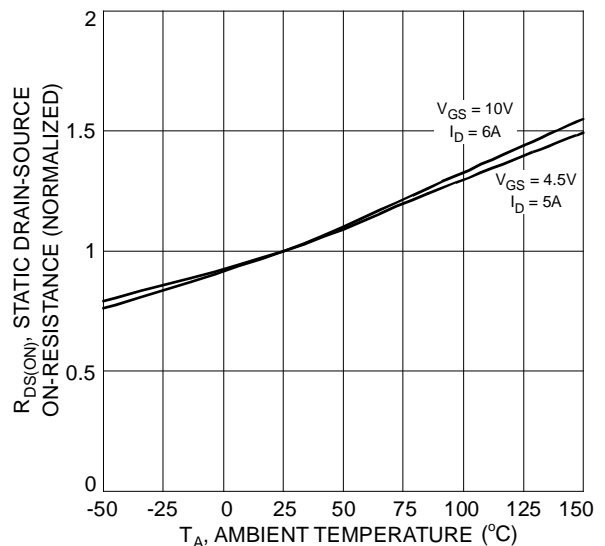
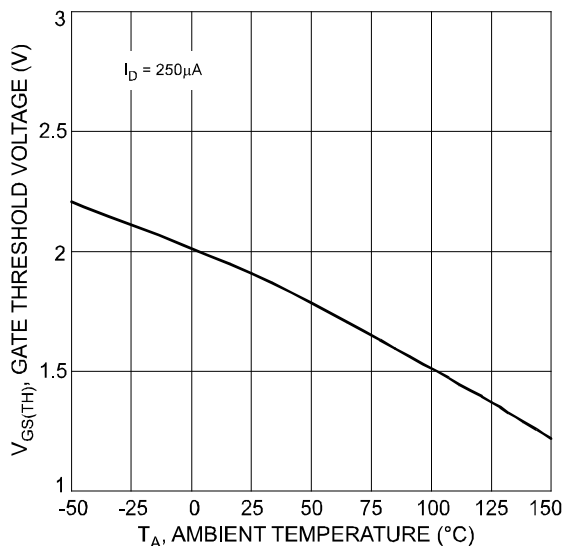
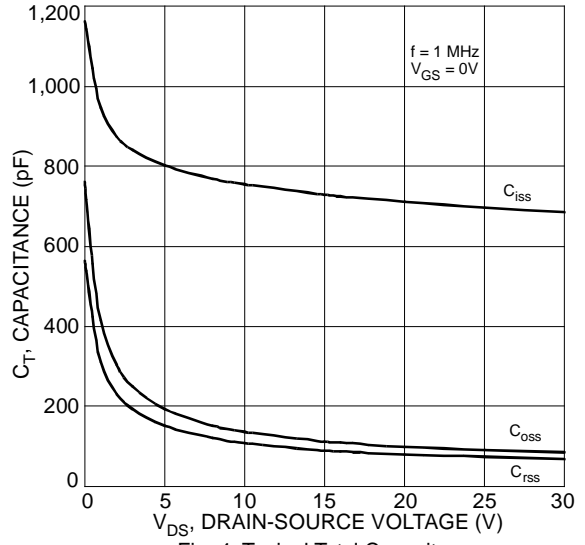
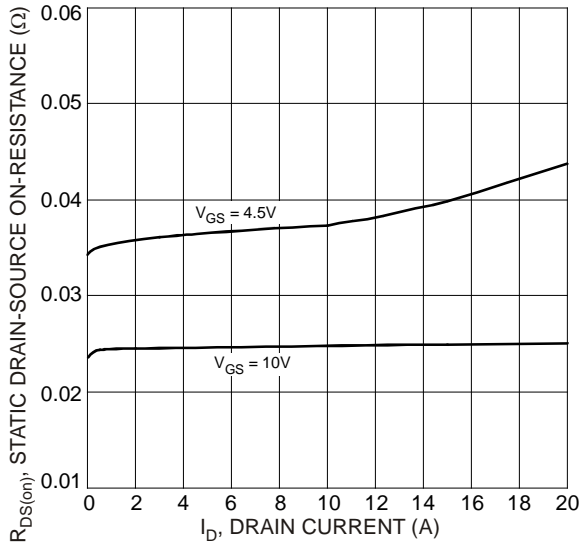
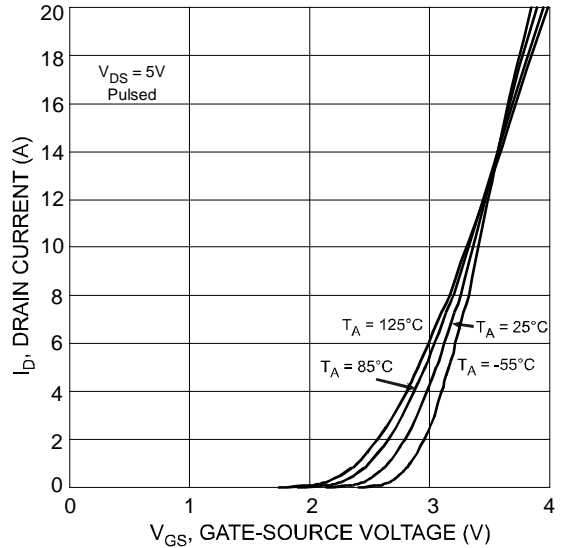
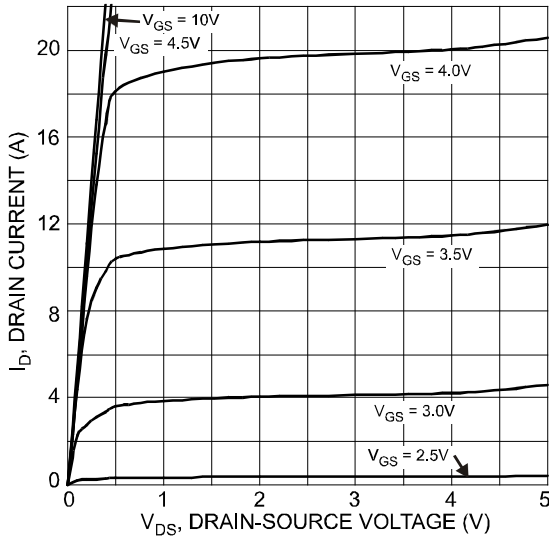
Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|----------------------------------------------------------|-----------------------------------|-------------|------|
| Total Power Dissipation (Note 5) | P _D | 1.4 | W |
| Thermal Resistance, Junction to Ambient (Note 5) t ≤ 10s | R _{θJA} | 90 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|--------------------------------------------|---------------------|-----|------|------|------|---------------------------------------------------------------------------------------------|
| STATIC PARAMETERS | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 30 | — | — | V | I _D = 250μA, V _{GS} = 0V |
| Zero Gate Voltage Drain Current | I _{DSS} | — | — | 1 | μA | V _{DS} = 30V, V _{GS} = 0V |
| | | | | 5 | | |
| Gate-Body Leakage Current | I _{GSS} | — | — | ±100 | nA | V _{DS} = 0V, V _{GS} = ±20V |
| Gate Threshold Voltage | V _{GS(TH)} | 1.0 | — | 2.1 | V | V _{DS} = V _{GS} , I _D = 250μA |
| Static Drain-Source On-Resistance (Note 7) | R _{DS(ON)} | — | 25 | 30 | mΩ | V _{GS} = 10V, I _D = 6A V _{GS} = 4.5V, I _D = 5A |
| | | | 36 | 40 | | |
| Forward Transconductance (Note 7) | g _{FS} | — | 5 | — | S | V _{DS} = 10V, I _D = 8A |
| Diode Forward Voltage (Note 7) | V _{SD} | — | 0.7 | 1.1 | V | I _S = 2.25A, V _{GS} = 0V |
| DYNAMIC PARAMETERS (Note 8) | | | | | | |
| Total Gate Charge | Q _g | — | 10.5 | — | nC | V _{GS} = 5V, V _{DS} = 15V, I _D = 6A |
| Gate-Source Charge | Q _{gs} | — | 3.8 | — | nC | V _{GS} = 10V, V _{DS} = 15V, I _D = 6A |
| Gate-Drain Charge | Q _{gd} | — | 2.9 | — | nC | V _{GS} = 10V, V _{DS} = 15V, I _D = 6A |
| Turn-On Delay Time | t _{D(ON)} | — | 11 | — | ns | V _{DD} = 15V, V _{GS} = 10V, R _D = 1.8Ω, R _G = 6Ω |
| Turn-On Rise Time | t _R | — | 7 | — | ns | |
| Turn-Off Delay Time | t _{D(OFF)} | — | 63 | — | ns | |
| Turn-Off Fall Time | t _F | — | 30 | — | ns | |
| Input Capacitance | C _{iss} | — | 755 | — | pF | V _{DS} = 10V, V _{GS} = 0V f = 1.0MHz |
| Output Capacitance | C _{oss} | — | 136 | — | pF | |
| Reverse Transfer Capacitance | C _{rss} | — | 108 | — | pF | |

- Notes:
- Device mounted on 1"x1", FR-4 PC board with 2 oz. Copper and test pulse width t ≤ 10s.
 - Repetitive Rating, pulse width limited by junction temperature.
 - Test pulse width t = 300ms.
 - Guaranteed by design. Not subject to production testing.



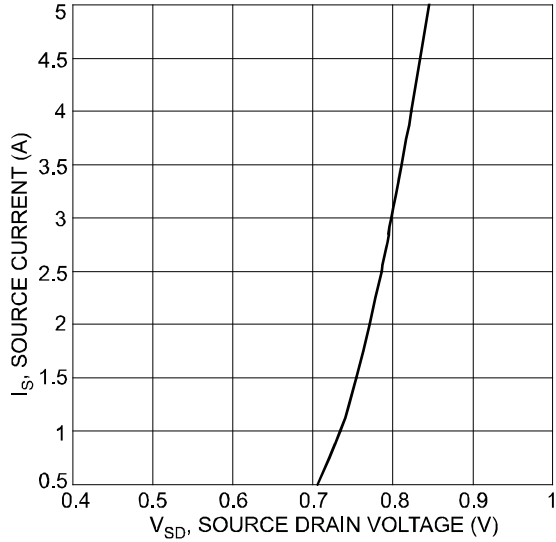
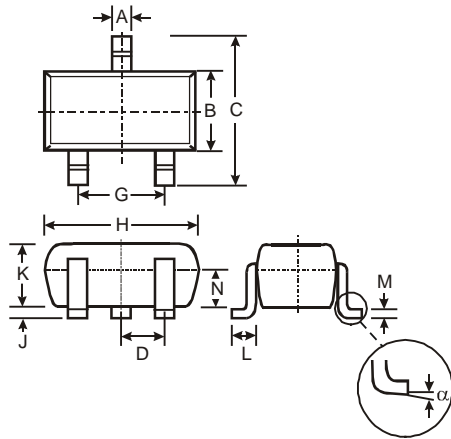


Fig. 7 Reverse Drain Current vs. Source-Drain Voltage

Package Outline Dimensions

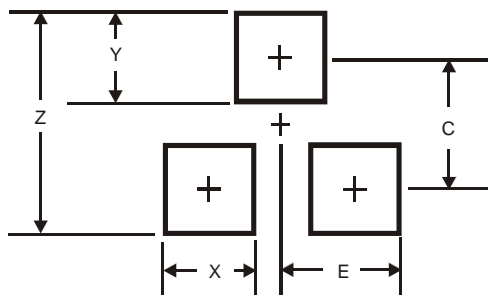
Please see <http://www.diodes.com/package-outlines.html> for the latest version.



| SC59 | | | |
|----------------------|-------|------|------|
| Dim | Min | Max | Typ |
| A | 0.35 | 0.50 | 0.38 |
| B | 1.50 | 1.70 | 1.60 |
| C | 2.70 | 3.00 | 2.80 |
| D | - | - | 0.95 |
| G | - | - | 1.90 |
| H | 2.90 | 3.10 | 3.00 |
| J | 0.013 | 0.10 | 0.05 |
| K | 1.00 | 1.30 | 1.10 |
| L | 0.35 | 0.55 | 0.40 |
| M | 0.10 | 0.20 | 0.15 |
| N | 0.70 | 0.80 | 0.75 |
| α | 0° | 8° | - |
| All Dimensions in mm | | | |

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 3.4 |
| X | 0.8 |
| Y | 1.0 |
| C | 2.4 |
| E | 1.35 |

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